

SANYO Semiconductors DATA SHEET

SBT150-06JS — Schottky Barrier Diode (Twin Type • Cathode Common) 60V, 15A Rectifier

Applications

· High frequency rectification (switching regulators, converters, choppers).

Features

- Tj=150°C.
- · Low forward voltage (VF max=0.58V).
- · Fast reverse recovery time.
- · Low switching noise.
- · High reliability due to planar structure.
- · Micaless package facitating easy mounting.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		60	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}		66	V
Average Output Current	IO	50Hz resistive load, sine wave Tc=90°C	15	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	100	Α
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
	Symbol		min	typ	max	Unit
Reverse Voltage	V _R	I _R =2mA, Tj=25°C *	60			V
Forward Voltage	VF	IF=6A, Tj=25°C *			0.58	V
Reverse Current	IR	V _R =30V, Tj=25°C *			0.2	mA

Note) * : Value per element

Continued on next page.

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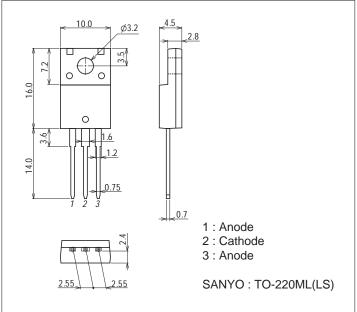
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Interterminal Capacitance	С	V _R =10V, Tj=25°C *		270		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			4.0	°C / W

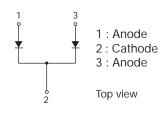
Note) * : Value per element

Package Dimensions

unit: mm (typ) 7525-001



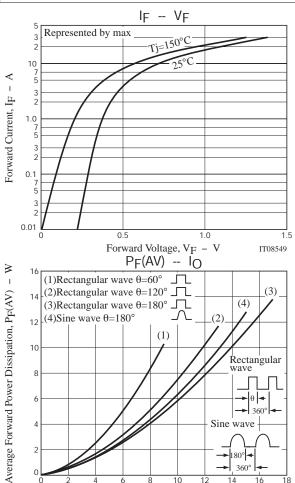
Electrical Connection



IR -- VR

100

10



(1)

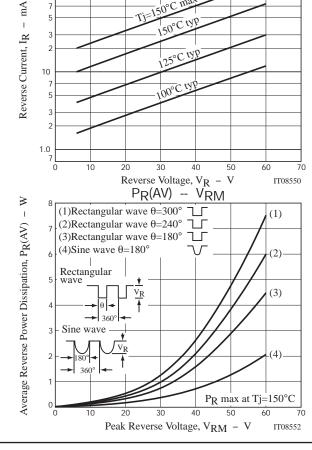
Average Output Current, $I_O - A$

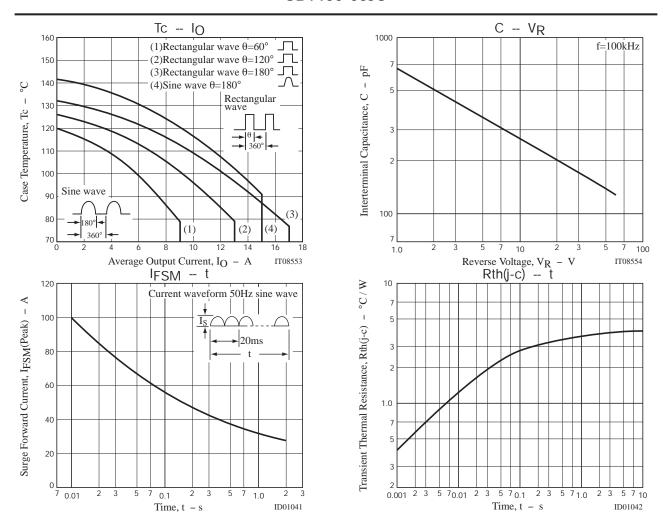
Rectangular wave

Sine wave

360°

IT08551





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